

# Mouad Bikerouin

## List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/3317261/publications.pdf>

Version: 2024-02-01

9

papers

95

citations

1478505

6

h-index

1474206

9

g-index

9

all docs

9

docs citations

9

times ranked

90

citing authors

| # | ARTICLE  | IF  | CITATIONS |
|---|--|-----|-----------|
| 1 | Strain effects on the electronic and optical properties of Van der Waals heterostructure MoS <sub>2</sub> /WS <sub>2</sub> : A first-principles study. <i>Physica E: Low-Dimensional Systems and Nanostructures</i> , 2020, 116, 113799. | 2.7 | 26        |
| 2 | Internal polarization electric field effects on the efficiency of InN/In <sub>x</sub> Al <sub>1-x</sub> N multiple quantum dot solar cells. <i>Solar Energy</i> , 2020, 201, 339-347.  | 6.1 | 16        |
| 3 | Electronic and optical properties of layered van der Waals heterostructure based on MS <sub>2</sub> (M = Mo, W) monolayers. <i>Materials Research Express</i> , 2019, 6, 065060.   | 1.6 | 13        |
| 4 | Linear and nonlinear optical properties of a single dopant in GaN conical quantum dot with spherical cap. <i>Philosophical Magazine</i> , 2020, 100, 2503-2523.  | 1.6 | 13        |
| 5 | Janus transition-metal dichalcogenides heterostructures for highly efficient excitonic solar cells. <i>Applied Surface Science</i> , 2022, 598, 153835.  | 6.1 | 11        |
| 6 | Effect of lattice deformation on electronic and optical properties of CuGaSe <sub>2</sub> : Ab-initio calculations. <i>Thin Solid Films</i> , 2020, 696, 137783.   | 1.8 | 9         |
| 7 | Electric field and strain induced gap modifications in multilayered GaN. <i>Applied Surface Science</i> , 2022, 578, 151970.   | 6.1 | 4         |
| 8 | Phonons correction of the energy and photoionization cross section in polar semiconductors and hollow nanoparticles. <i>Journal of Materials Research</i> , 2020, 35, 2077-2086.   | 2.6 | 2         |
| 9 | Prediction of optoelectronic features and efficiency for CuMX <sub>2</sub> (M=Ga, In; X=S, Se) semiconductors using mbj+U approximation. <i>Current Applied Physics</i> , 2021, 32, 11-23.   | 2.4 | 1         |